

IR2117(S)/IR2118(S) & (PbF)

International
IR Rectifier

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Additional information is shown in Figures 5 through 8.

Symbol	Definition	Min.	Max.	Units
V_B	High side floating supply voltage	-0.3	625	V
V_S	High side floating supply offset voltage	$V_B - 25$	$V_B + 0.3$	
V_{HO}	High side floating output voltage	$V_S - 0.3$	$V_B + 0.3$	
V_{CC}	Logic supply voltage	-0.3	25	
V_{IN}	Logic input voltage	-0.3	$V_{CC} + 0.3$	
dV_S/dt	Allowable offset supply voltage transient (figure 2)	—	50	V/ns
P_D	Package power dissipation @ $T_A \leq +25^\circ\text{C}$ (8 lead PDIP)	—	1.0	W
	(8 lead SOIC)	—	0.625	
R_{thJA}	Thermal resistance, junction to ambient (8 lead PDIP)	—	125	$^\circ\text{C}/\text{W}$
	(8 lead SOIC)	—	200	
T_J	Junction temperature	—	150	$^\circ\text{C}$
T_S	Storage temperature	-55	150	
T_L	Lead temperature (soldering, 10 seconds)	—	300	

Recommended Operating Conditions

The input/output logic timing diagram is shown in figure 1. For proper operation the device should be used within the recommended conditions. The V_S offset rating is tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
V_B	High side floating supply absolute voltage	$V_S + 10$	$V_S + 20$	V
V_S	High side floating supply offset voltage	Note 1	600	
V_{HO}	High side floating output voltage	V_S	V_B	
V_{CC}	Logic supply voltage	10	20	
V_{IN}	Logic input voltage	0	V_{CC}	
T_A	Ambient temperature	-40	125	$^\circ\text{C}$

Note 1: Logic operational for V_S of -5 to +600V. Logic state held for V_S of -5V to $-V_{BS}$. (Please refer to the Design Tip DT97-3 for more details).

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Dynamic Electrical Characteristics

V_{BIAS} (V_{CC} , V_{BS}) = 15V, C_L = 1000 pF and T_A = 25°C unless otherwise specified. The dynamic electrical characteristics are measured using the test circuit shown in Figure 3.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
t_{on}	Turn-on propagation delay	—	125	200	ns	$V_S = 0V$
t_{off}	Turn-off propagation delay	—	105	180		$V_S = 600V$
t_r	Turn-on rise time	—	80	130		
t_f	Turn-off fall time	—	40	65		

Static Electrical Characteristics

V_{BIAS} (V_{CC} , V_{BS}) = 15V and T_A = 25°C unless otherwise specified. The V_{IN} , V_{TH} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
V_{IH}	input voltage - logic "1" (IR2117) logic "0" (IR2118)	9.5	—	—	V	
V_{IL}	Input voltage - logic "0" (IR2117) logic "1" (IR2118)	—	—	6.0		
V_{OH}	High level output voltage, $V_{BIAS} - V_O$	—	—	100	mV	$I_O = 0A$
V_{OL}	Low level output voltage, V_O	—	—	100		$I_O = 0A$
I_{LK}	Offset supply leakage current	—	—	50	μA	$V_B = V_S = 600V$
I_{QBS}	Quiescent V_{BS} supply current	—	50	240		$V_{IN} = 0V$ or V_{CC}
I_{QCC}	Quiescent V_{CC} Supply Current	—	70	340		$V_{IN} = 0V$ or V_{CC}
I_{IN+}	Logic "1" input bias current (IR2117)	—	20	40		$V_{IN} = V_{CC}$
	(IR2118)	—	—	—		$V_{IN} = 0V$
I_{IN-}	Logic "0" input bias current (IR2117)	—	—	1.0		$V_{IN} = 0V$
	(IR2118)	—	—	—		$V_{IN} = V_{CC}$
V_{BSUV+}	V_{BS} supply undervoltage positive going threshold	7.6	8.6	9.6	V	
V_{BSUV-}	V_{BS} supply undervoltage negative going threshold	7.2	8.2	9.2		
V_{CCUV+}	V_{CC} supply undervoltage positive going threshold	7.6	8.6	9.6		
V_{CCUV-}	V_{CC} supply undervoltage negative going threshold	7.2	8.2	9.2		
I_{O+}	Output high short circuit pulsed current	200	250	—	mA	$V_O = 0V$ $V_{IN} = \text{Logic "1"}$ $PW \leq 10 \mu s$
I_{O-}	Output low short circuit pulsed current	420	500	—		$V_O = 15V$ $V_{IN} = \text{Logic "0"}$ $PW \leq 10 \mu s$

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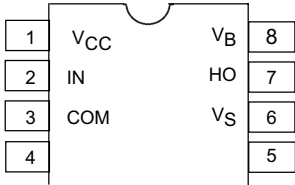
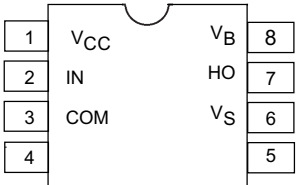
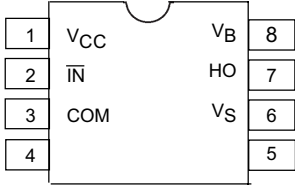
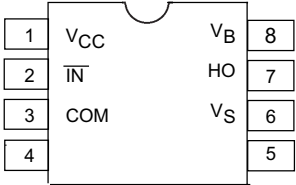
The schematic diagram illustrates the UV detector circuit. It features an input terminal 'IN' connected to a resistor and a voltage divider network. The input signal is processed by a buffer (labeled '1') and a UV DETECT block. The output of the UV DETECT block is connected to an AND gate. The other input of the AND gate is connected to a PULSE GEN block. The output of the AND gate is connected to the PULSE GEN block. The PULSE GEN block is connected to an HV LEVEL SHIFT block. The output of the HV LEVEL SHIFT block is connected to a UV DETECT block and a PULSE FILTER block. The output of the PULSE FILTER block is connected to an R-S flip-flop. The output of the R-S flip-flop is connected to a driver stage consisting of two transistors. The driver stage is connected to the output terminal 'HO' and a voltage source 'V_S'. The circuit is powered by 'V_{CC}' and 'COM' (connected to ground).

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Lead Definitions

Symbol	Description
V _{CC}	Logic and gate drive supply
IN	Logic input for gate driver output (HO), in phase with HO (IR2117)
$\overline{\text{IN}}$	Logic input for gate driver output (HO), out of phase with HO (IR2118)
COM	Logic ground
V _B	High side floating supply
HO	High side gate drive output
V _S	High side floating supply return

Lead Assignments

 8 Lead PDIP IR2117	 8 Lead SOIC IR2117S
 8 Lead PDIP IR2118	 8 Lead SOIC IR2118S

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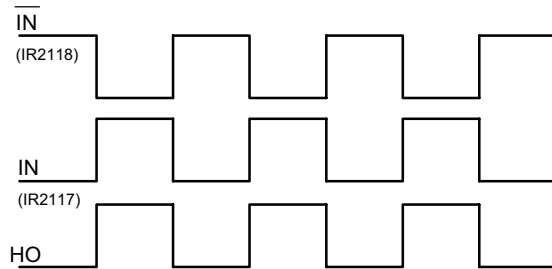


Figure 1. Input/Output Timing Diagram

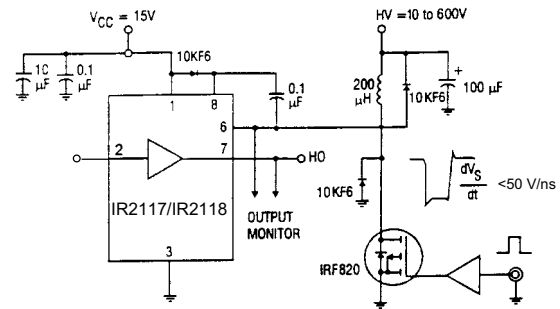


Figure 2. Floating Supply Voltage Transient Test Circuit

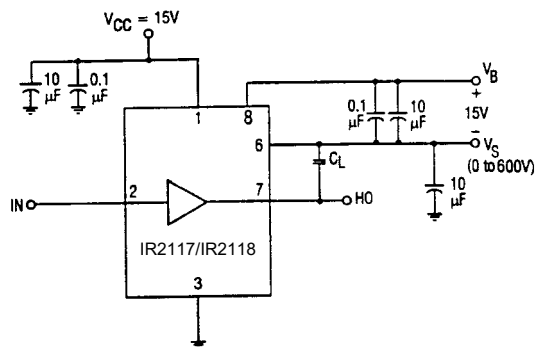


Figure 3. Switching Time Test Circuit

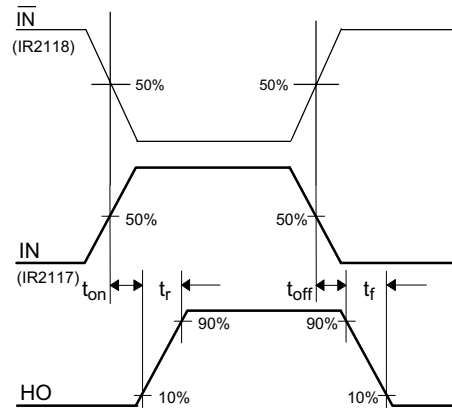


Figure 4. Switching Time Waveform Definition

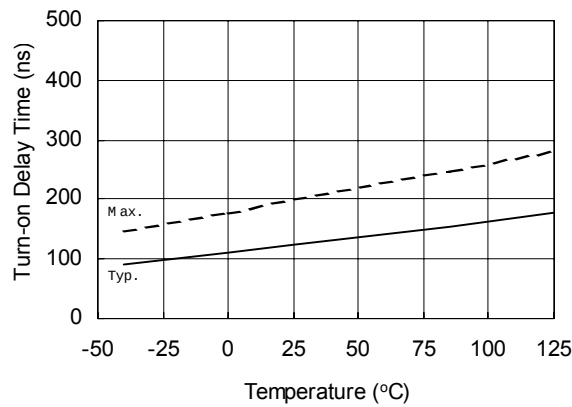


Figure 4A. Turn-On Time vs. Temperature

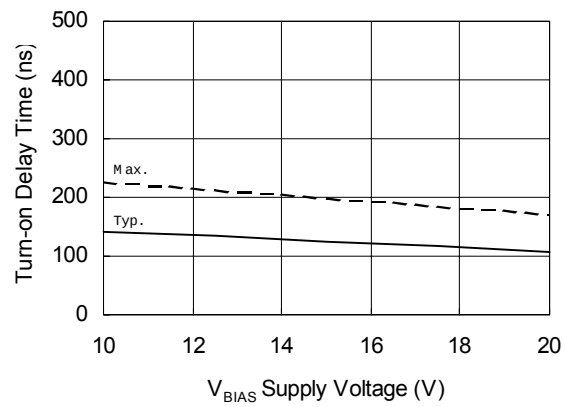


Figure 4B. Turn-On Time vs. Supply Voltage

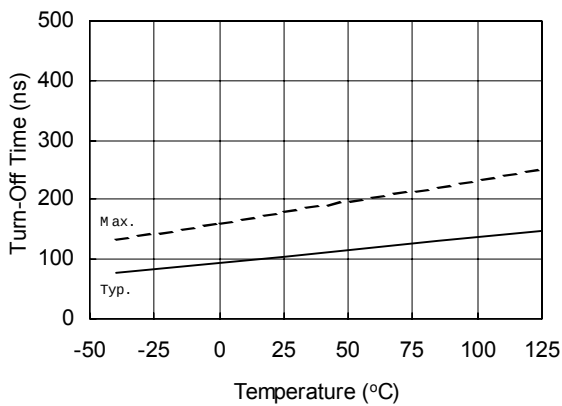


Figure 5A. Turn-Off Time vs. Temperature

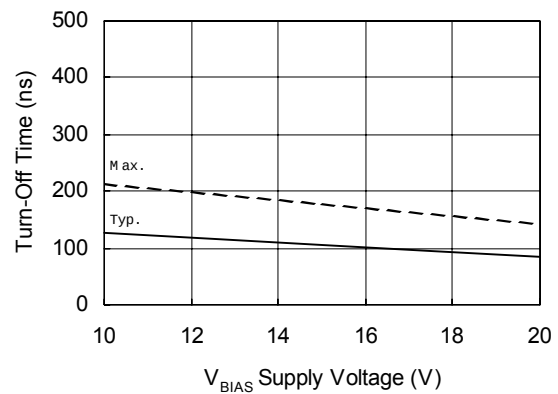


Figure 5B. Turn-Off Time vs. Supply Voltage

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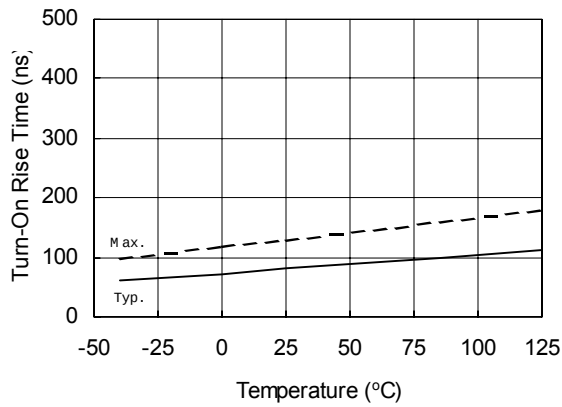


Figure 6A. Turn-On Rise Time vs. Temperature

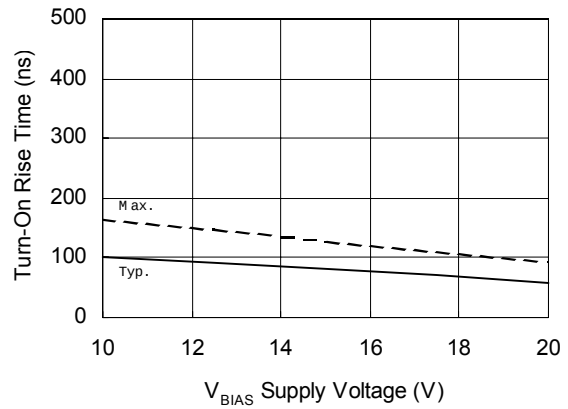


Figure 6B. Turn-On Rise Time vs. Supply Voltage

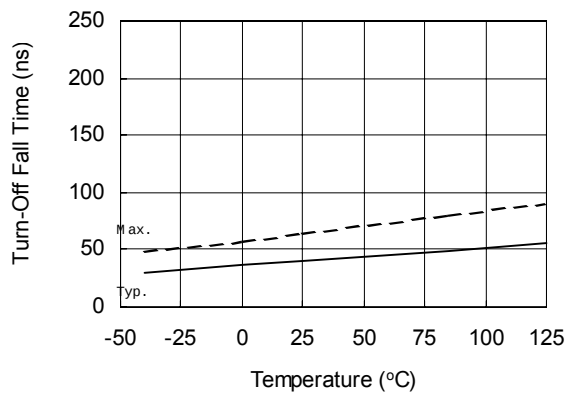


Figure 7A. Turn-Off Fall Time vs. Temperature

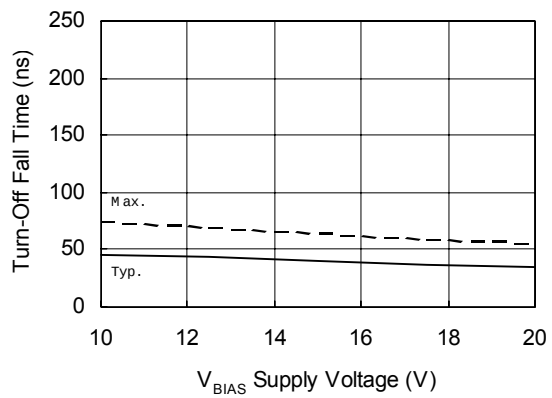


Figure 7B. Turn-Off Fall Time vs. Supply Voltage

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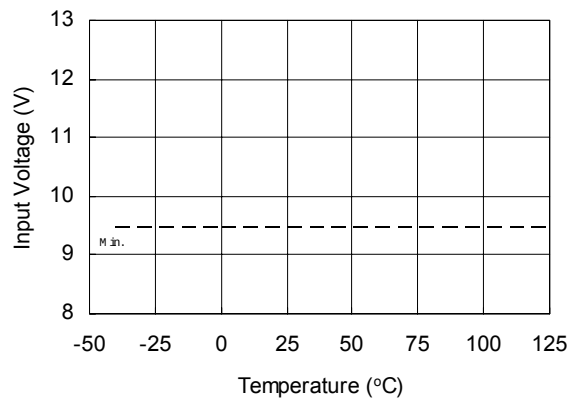


Figure 8A. Logic "1" (IR2118 "0") Input Voltage vs. Temperature

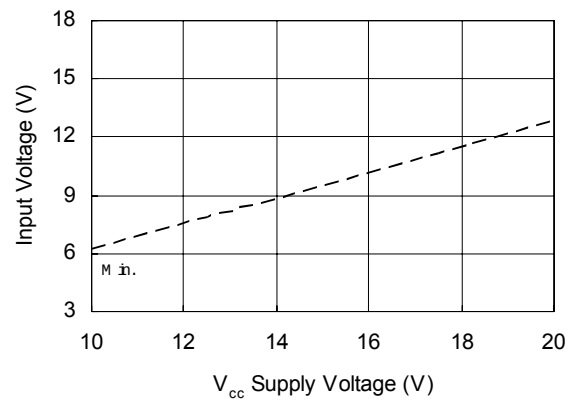


Figure 8B. Logic "1" (IR2118 "0") Input Voltage vs. Supply Voltage

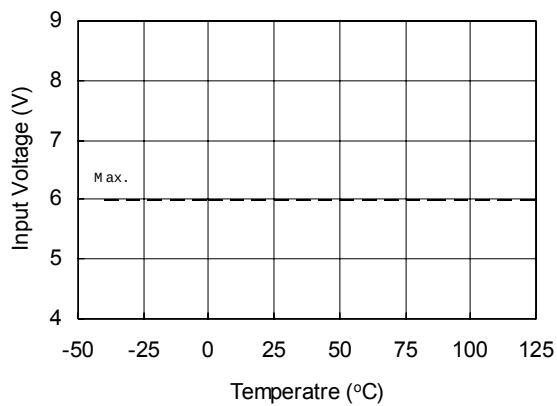


Figure 9A. Logic "0" (IR2118 "1") Input Voltage vs. Temperature

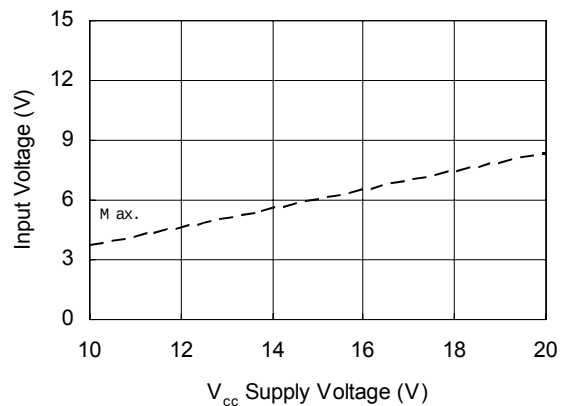


Figure 9B. Logic "0" (IR2118 "1") Input Voltage vs. Supply Voltage

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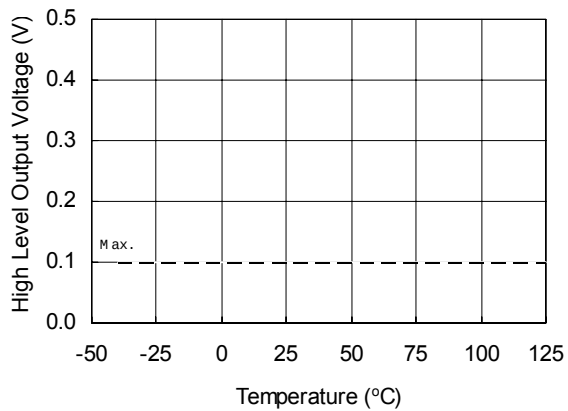


Figure 10A. High Level Output vs. Temperature

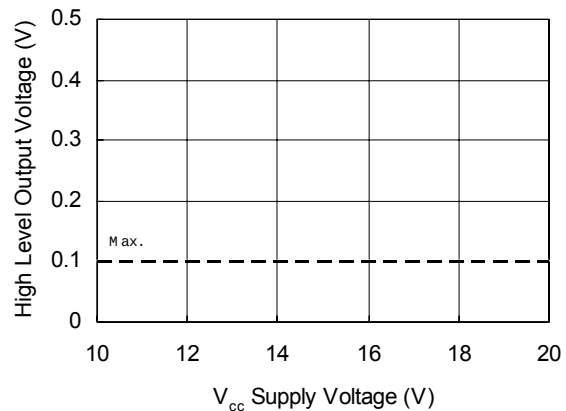


Figure 10B. High Level Output vs. Supply Voltage

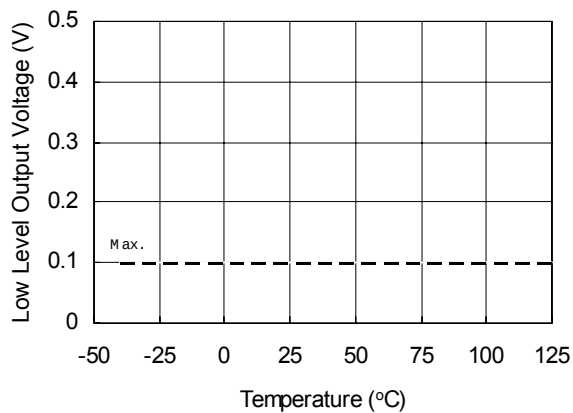


Figure 11A. Low Level Output vs. Temperature

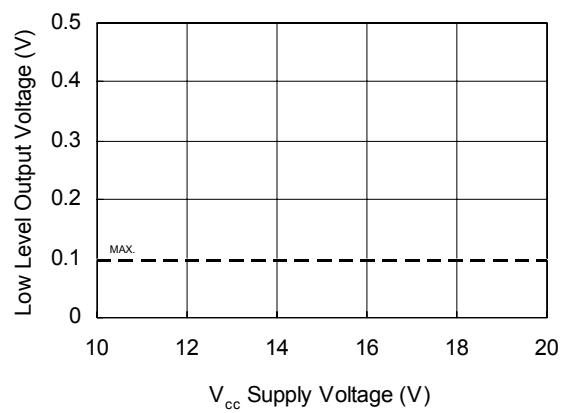


Figure 11B. Low Level Output vs. Supply Voltage

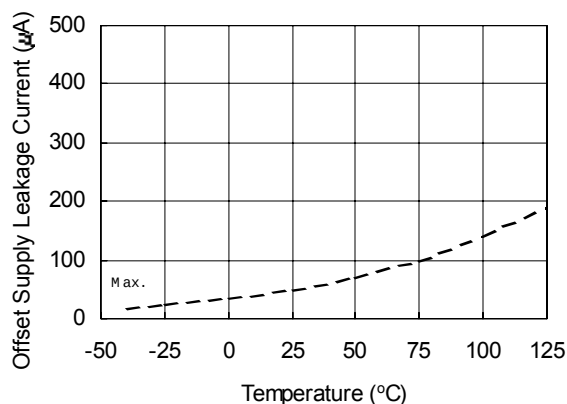


Figure 12A. Offset Supply Leakage Current vs. Temperature

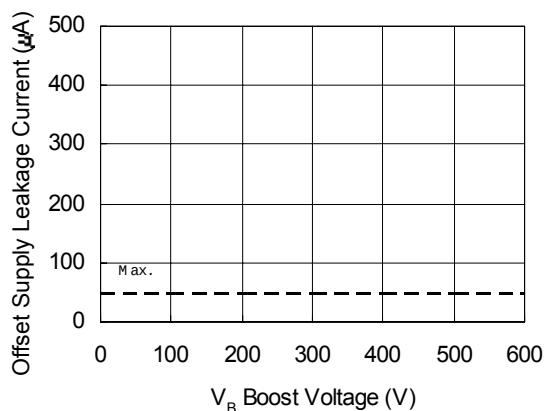


Figure 12B. Offset Supply Leakage Current vs. V_B Boost Voltage

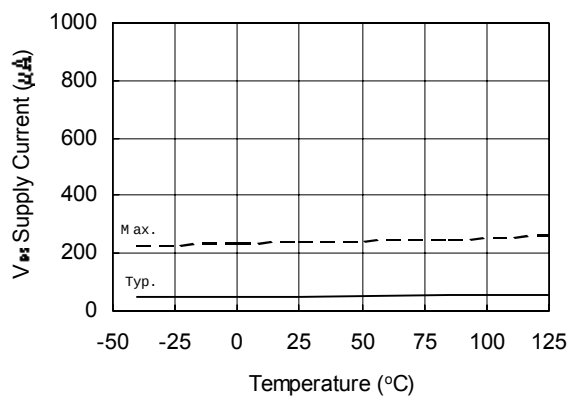


Figure 13A. V_{BS} Supply Current vs. Temperature

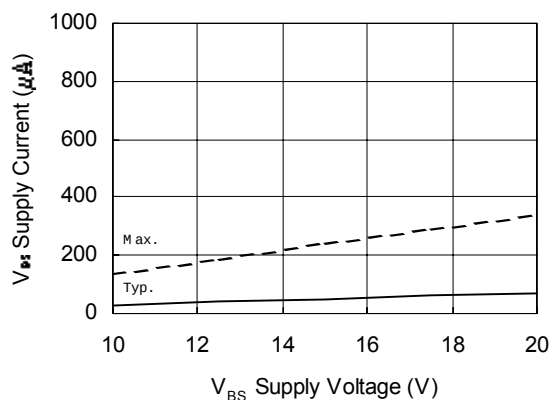


Figure 13B. V_{BS} Supply Current vs. Supply Voltage

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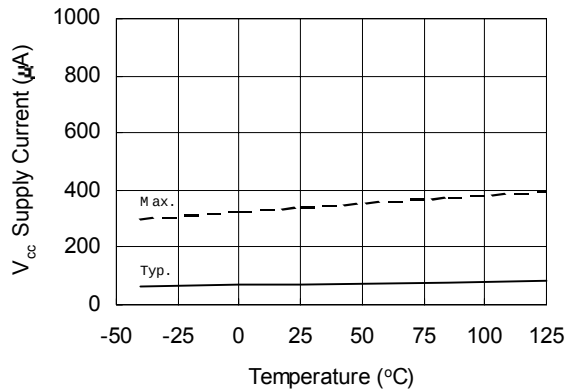


Figure 14A. V_{cc} Supply Current vs. Temperature

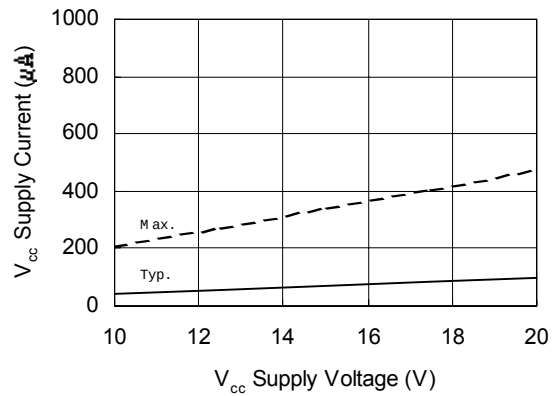


Figure 14B. V_{cc} Supply Current vs. Supply Voltage

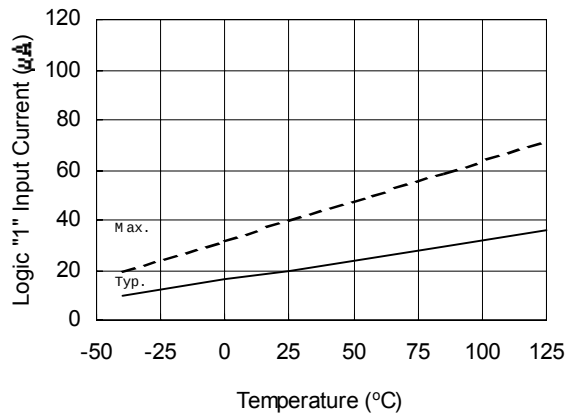


Figure 15A. Logic "1" (2118 "0") Input Current vs. Temperature

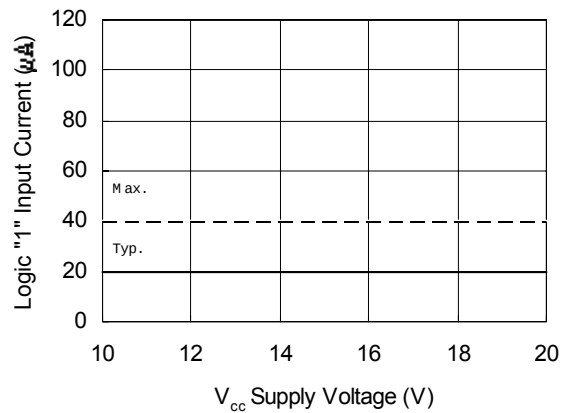


Figure 15B. Logic "1" (2118 "0") Input Current vs. Supply Voltage

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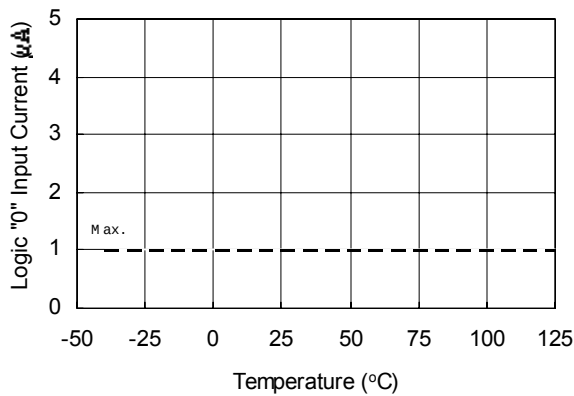


Figure 16A. Logic "0" (2118"1") Input Current vs. Temperature

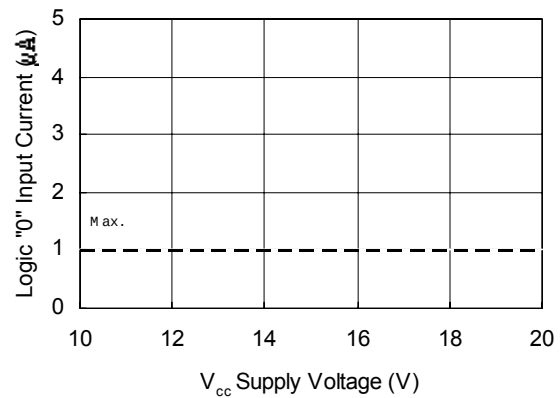


Figure 16B. Logic "0" (2118"1") Input Current vs. Supply Voltage

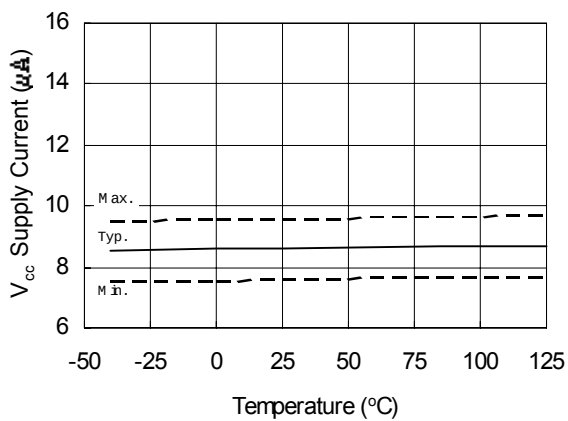


Figure 17A. V_{cc} Undervoltage Threshold (+) vs. Temperature

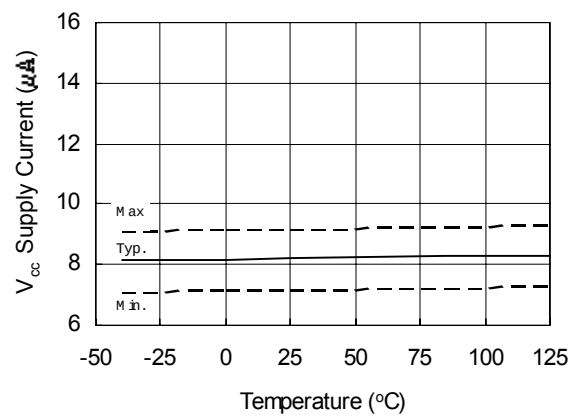


Figure 18A. V_{cc} Undervoltage Threshold (-) vs. Temperature

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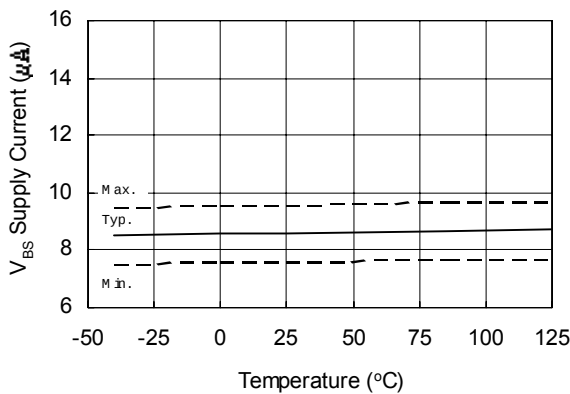


Figure 19A. V_{BS} Undervoltage Threshold (+) vs. Temperature

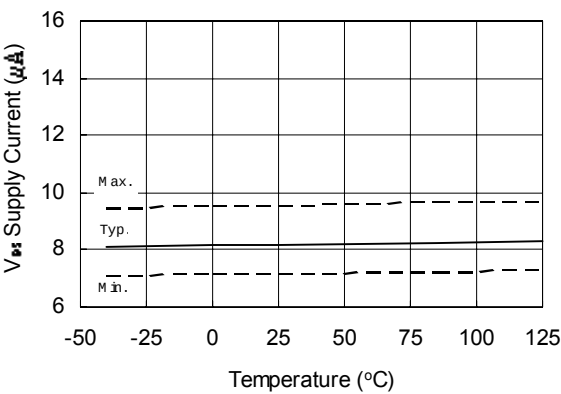


Figure 20A. V_{BS} Undervoltage Threshold (-) vs. Temperature

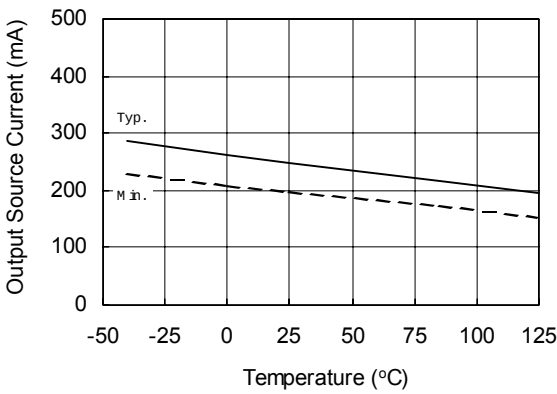


Figure 21A. Output Source Current vs. Temperature

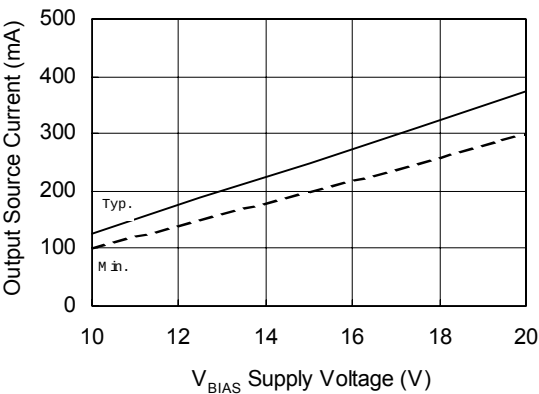


Figure 21B. Output Source Current vs. Supply Voltage

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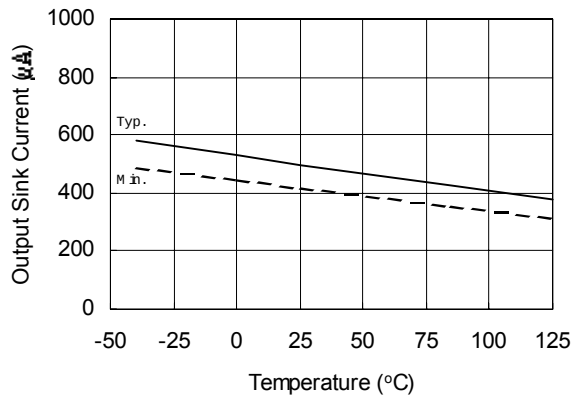


Figure 22A. Output Sink Current vs. Temperature

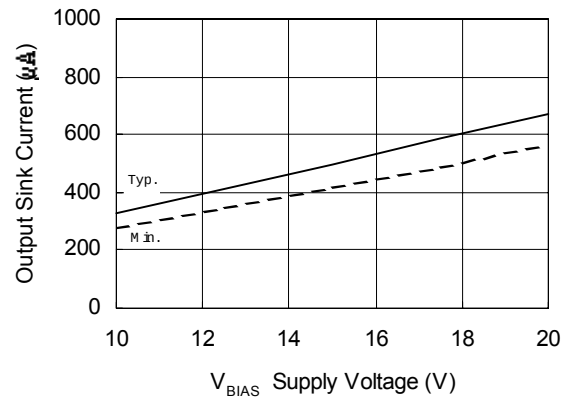


Figure 22B. Output Sink Current vs. Supply Voltage

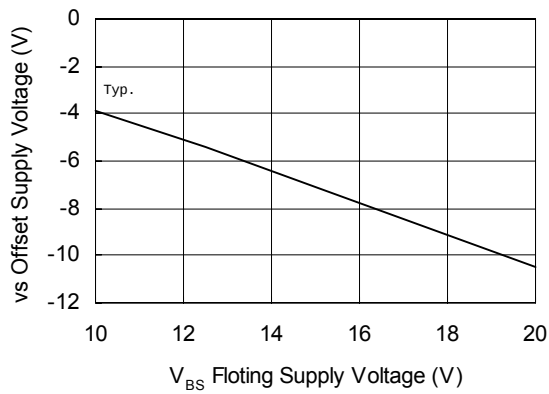


Figure 23B. Maximum VS Negative Offset vs. Supply Voltage

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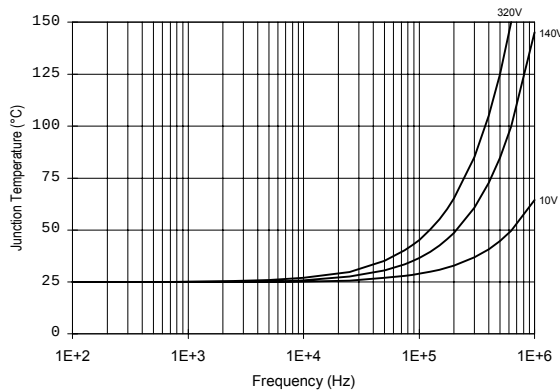


Figure 24. IR2117/IR2118 T_J vs. Frequency (IRFBC20)
 $R_{GATE} = 33\Omega$, $V_{CC} = 15V$

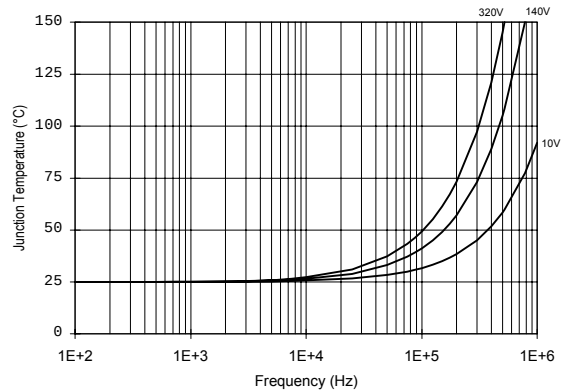


Figure 25. IR2117/IR2118 T_J vs. Frequency (IRFBC30)
 $R_{GATE} = 22\Omega$, $V_{CC} = 15V$

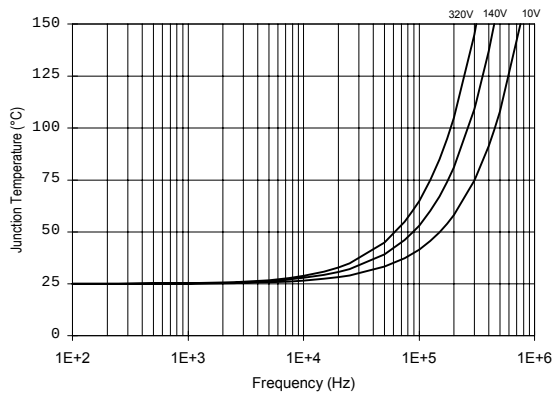


Figure 26. IR2117/IR2118 T_J vs. Frequency (IRFBC40)
 $R_{GATE} = 15\Omega$, $V_{CC} = 15V$

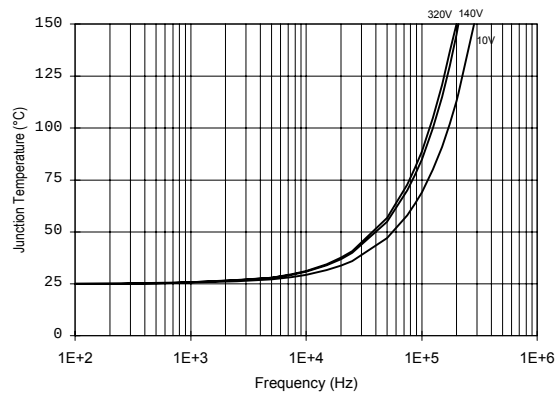
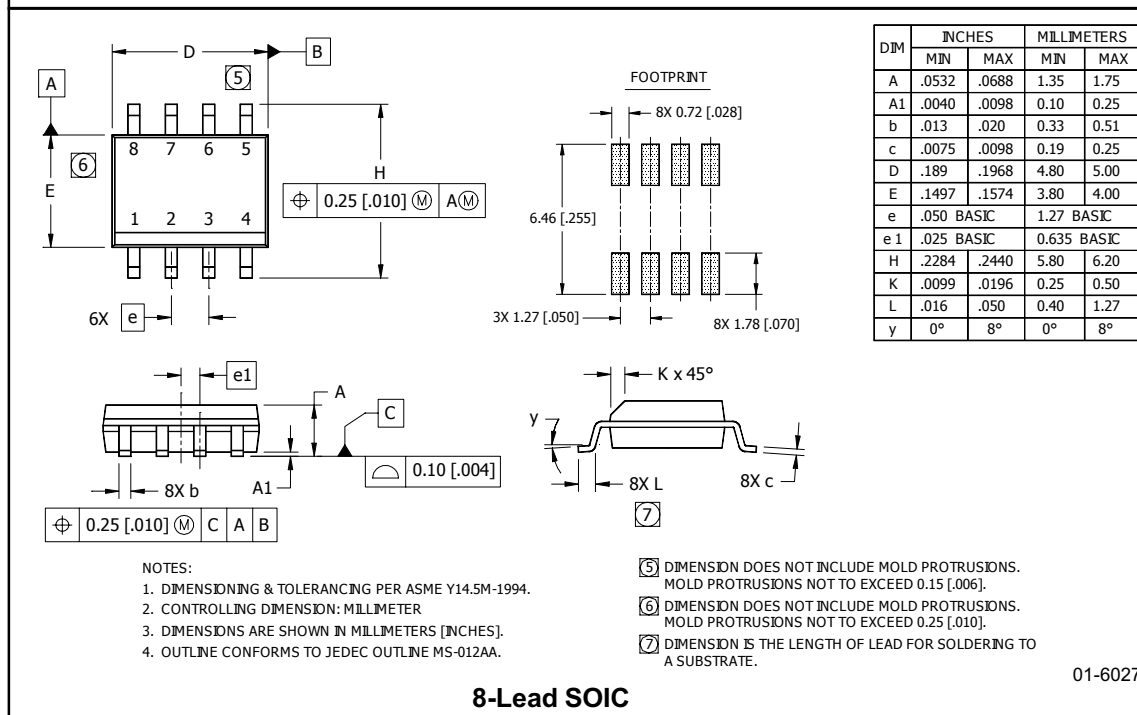
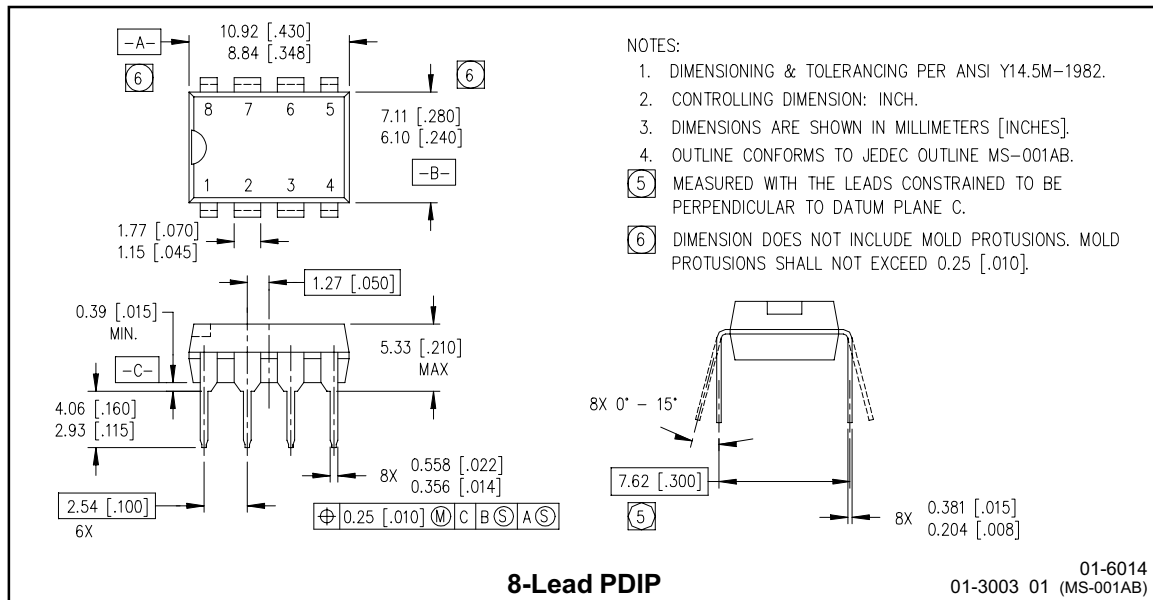


Figure 27. IR2117/IR2118 T_J vs. Frequency (IRFPE50)
 $R_{GATE} = 10\Omega$, $V_{CC} = 15V$

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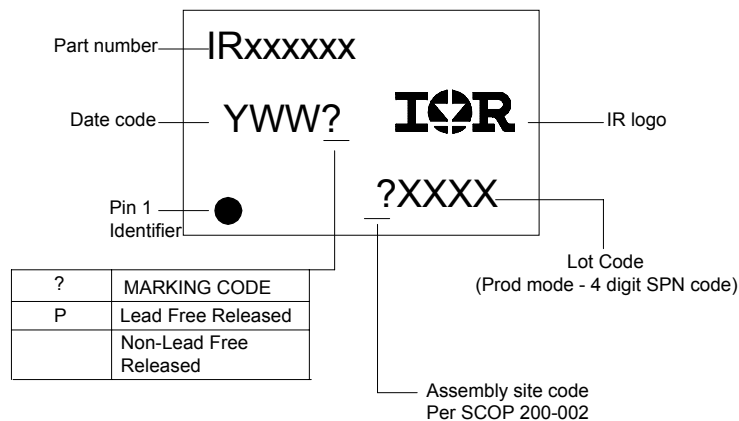
Case outlines



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LEADFREE PART MARKING INFORMATION



ORDER INFORMATION

Basic Part (Non-Lead Free)

8-Lead PDIP IR2117 order IR2117
8-Lead PDIP IR2118 order IR2118
8-Lead SOIC IR2117S order IR2117S
8-Lead SOIC IR2118S order IR2118S

Leadfree Part

8-Lead PDIP IR2117 order IR2117PbF
8-Lead PDIP IR2118 order IR2118PbF
8-Lead SOIC IR2117S order IR2117SPbF
8-Lead SOIC IR2118S order IR2118SPbF

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IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245 Tel: (310) 252-7105

This product has been qualified per industrial level

Data and specifications subject to change without notice. 5/14/2007